



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	110mΩ @ V _{GS} = -10V	-4.2A
-60V	130mΩ @ V _{GS} = -4.5V	-3.9A

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Notes 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMP6110SFDFQ</u>)

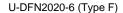
Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

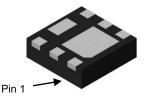
- Battery Management Application
- Power Management Functions
- DC-DC Converters

Mechanical Data

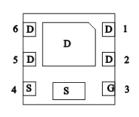
- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208⁽³⁾
- Weight: 0.007 grams (Approximate)



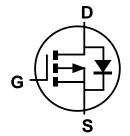




Top View Bottom View



Pin Out Bottom View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging		
DMP6110SFDF-7	U-DFN2020-6 (Type F)	3,000/Tape & Reel		
DMP6110SFDF-13	U-DFN2020-6 (Type F)	10,000/Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



P0 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	С		Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



P0 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	5		0	1	2	3	4	5	6	7	8	9
Week	1-26					27-	-52		53			
Code		Α	-Z			a-	-Z			7	Z	
Internal Code	Sur	1	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Υ		Z



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	VDSS	-60	V		
Gate-Source Voltage	V_{GSS}	±20	V		
Continuous Drain Current (Note 6) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lo	-3.5 -2.8	А
Continuous Drain Current (Note 6) V _{GS} = -10V	$T_A = +25$ °C $T_A = +70$ °C	lo	-4.2 -3.4	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I_{DM}	-20	Α
Continuous Source-Drain Diode Current (Note 6)	Is	-2.1	Α		
Avalanche Current (Note 7) L = 0.1mH	las	-19	А		
Avalanche Energy (Note 7) L = 0.1mH			Eas	18	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)	T _A = +25°C	Pn	0.76	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.47	VV	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R ₀ JA	167	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	Keja	121	C/VV	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	D-	1.97	W	
Total Fower Dissipation (Note 0)	$T_A = +70^{\circ}C$	P _D	1.30	VV	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Dov	64	 [
Thermal Resistance, Junction to Ambient (Note o)	t<10s	Reja	42	°C/W	
Thermal Resistance, Junction to Case (Note 6) Stea		Rejc	8		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-1	μΑ	V _{DS} = -48V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						·
Gate Threshold Voltage	Vgs(TH)	-1	_	-3	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$
Static Drain-Source On-Resistance	D		_	110	mΩ	$V_{GS} = -10V, I_D = -4.5A$
Static Drain-Source On-Resistance	RDS(ON)	_	_	130	11177	$V_{GS} = -4.5V, I_D = -3.5A$
Diode Forward Voltage	VsD	_	-0.7	-1.2	V	V _G S = 0V, I _S = -1A
DYNAMIC CHARACTERISTICS (Note 9)					•	•
Input Capacitance	Ciss	_	969	_		.,
Output Capacitance	Coss	_	58	_	pF	V _{DS} = -30V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	44	_		1.0IVIHZ
Gate Resistance	Rg	_	14	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$
Total Gate Charge (V _{GS} = -4.5V)	Q _G	_	8.2	_		
Total Gate Charge (V _{GS} = -10V)	Qg	_	17.2	_	nC	N/ 00N/ 1 40A
Gate-Source Charge	Qgs	_	3.0	_	nc nc	V _{DS} = -30V, I _D = -12A
Gate-Drain Charge	Q _{GD}	_	3.1	_		
Turn-On Delay Time	tD(ON)	_	4.4	_		
Turn-On Rise Time	t _R	_	23	_		V _{GS} = -10V, V _{DS} = -30V, R _{GEN} =
Turn-Off Delay Time	tD(OFF)	_	34	_	ns	6Ω, I _D = -12A
Turn-Off Fall Time	tF	_	42	_		
Reverse Recovery Time	t _{RR}	_	13.2	_	ns	I _S = -12A, di/dt = -100A/µs
Reverse Recovery Charge	Qrr	_	6.2	_	nC	Is = -12A, di/dt = -100A/us

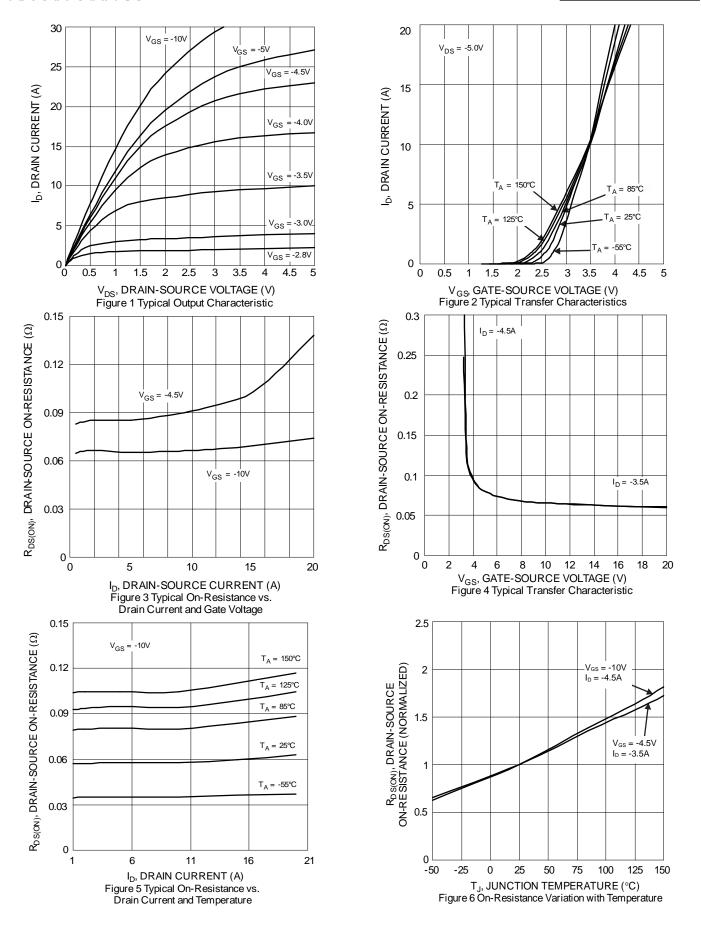
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

^{7.} I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

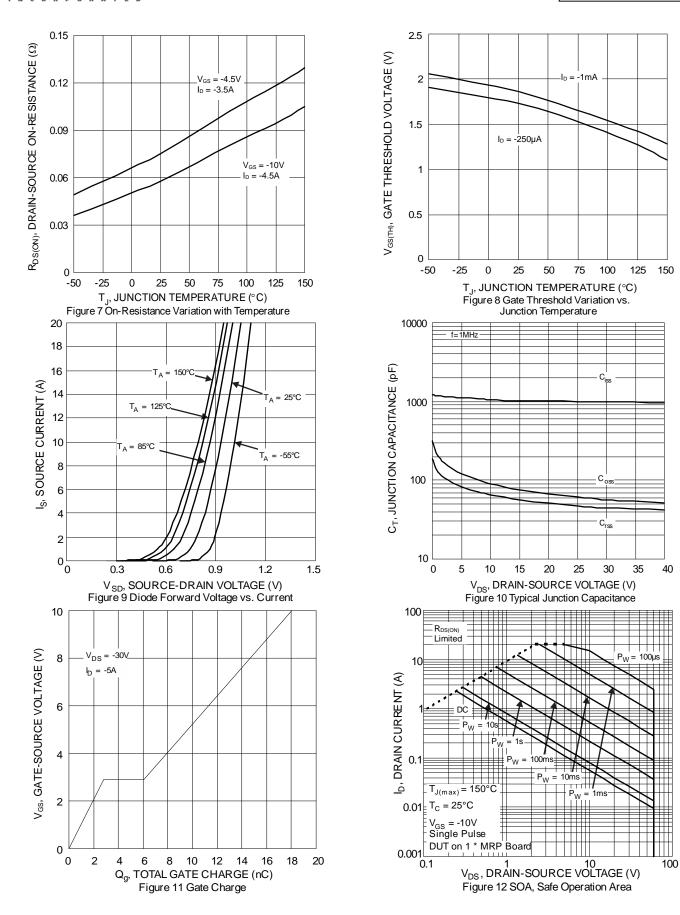
^{8.} Short duration pulse test used to minimize self-heating effect.

^{9.} Guaranteed by design. Not subject to product testing.

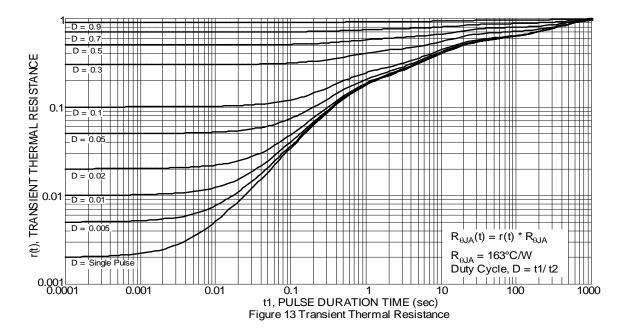










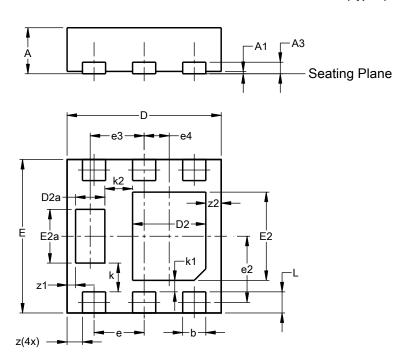




Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)

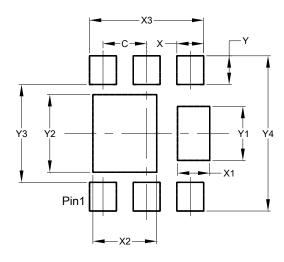


U-DFN2020-6 (Type F)						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0.00	0.05	0.03			
A3	-	-	0.15			
b	0.25	0.35	0.30			
D	1.95	2.05	2.00			
D2	0.85	1.05	0.95			
D2a	0.33	0.43	0.38			
Е	1.95	2.05	2.00			
E2	1.05	1.25	1.15			
E2a	0.65	0.75	0.70			
е		0.65 BS	С			
e2	().863 BS	SC .			
е3		0.70 BS				
e4).325 BS				
k	0.37 BSC					
k1	0.15 BSC					
k2	0.36 BSC					
L		0.325				
Z		0.20 BS				
z1).110 BS				
z2		0.20 BS				
All D	imens	ions in	mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value
Dillicitatoria	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
Х3	1.700
Υ	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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